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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Serial No.:

JOSEPH T. EVANS, JR. ET AL.

Filed:

582,672

Group:

September 14, 1990

233

Examiner:

Alyssa H. Bowler

For:

NON-VOLATILE MEMORY CIRCUIT USING
FERROELECTRIC CAPACITOR STORAGE ELEMENT

Honorable Commissioner of
Patents and Trademarks
Washington, D.C. 20231

RECEIVED

JUL 11 1991

GROUP 230

Dear Sir:

AMENDMENT AND RESPONSE

In response to the Office Action mailed February 7, 1991, please amend the above-identified application in the following manner.

IN THE SPECIFICATION

Page 4, line 8, after "drive", insert --lines--.
Page 4, line 11, change "through" to --of--.
Page 4, line 19, after "capacitor", insert a comma.
Page 4, line 29, after "plurality", insert --of--.
Page 4, line 30, change "state" to --states--.
Page 4, lines 31 and 33, after "capacitor", insert a comma.

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to:
Commissioner of Patents and Trademarks,

Washington, D.C. 20231 on July 8, 1991
(Date of Deposit)
Roger N. Chauza, Reg. No. 29,753

Name of applicant, assignee, or
Registered Representative

Roger N. Chauza
Signature

JULY 8, 1991
Date of Signature